

Dual Supply Octal Translating Transceiver with 3-State Outputs

MC74LVX4245

The 74LVX4245 is a 24-pin dual-supply, octal translating transceiver that is designed to interface between a 5.0 V bus and a 3.0 V bus in a mixed 3.0 V / 5.0 V supply environment such as laptop computers using a 3.3 V CPU and 5.0 V LCD display. The A port interfaces with the 5V bus; the B port interfaces with the 3.0 V bus.

The Transmit/Receive (T/R) input determines the direction of data flow. Transmit (active-High) enables data from the A port to the B port. Receive (active-Low) enables data from the B port to the A port. The Output Enable (\overline{OE}) input, when High, disables both A and B ports by placing them in 3-State.

Features

- Bi-directional Interface Between 5.0 V and 3.0 V Buses
- Control Inputs Compatible with TTL Level
- 5.0 V Data Flow at A Port and 3.0 V Data Flow at B Port
- Outputs Source/Sink 24 mA at 5.0 V Bus and 12 mA at 3.0 V Bus
- Guaranteed Simultaneous Switching Noise Level and Dynamic Threshold Performance
- Available in SOIC and TSSOP Packages
- Functionally Compatible with the 74 Series 245
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

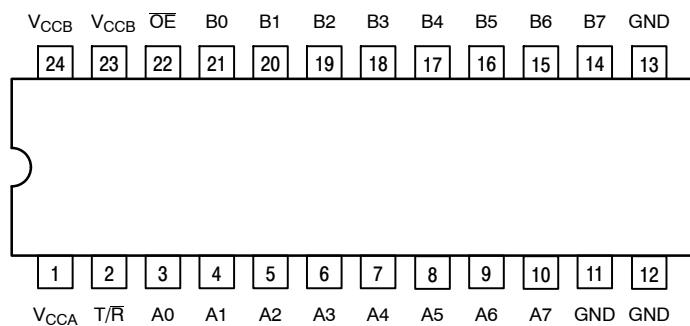
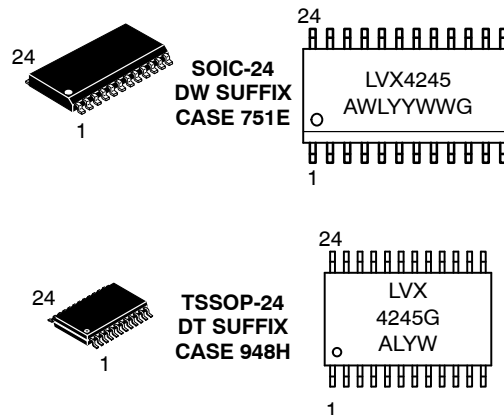


Figure 1. 24-Lead Pinout (Top View)

MARKING DIAGRAMS



LVX4245 = Specific Device Code
 A = Assembly Location
 WL, L = Wafer Lot
 Y = Year
 WW, W = Work Week
 G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

PIN NAMES

Pins	Function
\overline{OE}	Output Enable Input
T/R	Transmit/Receive Input
A0–A7	Side A 3-State Inputs or 3-State Outputs
B0–B7	Side B 3-State Inputs or 3-State Outputs

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 5.

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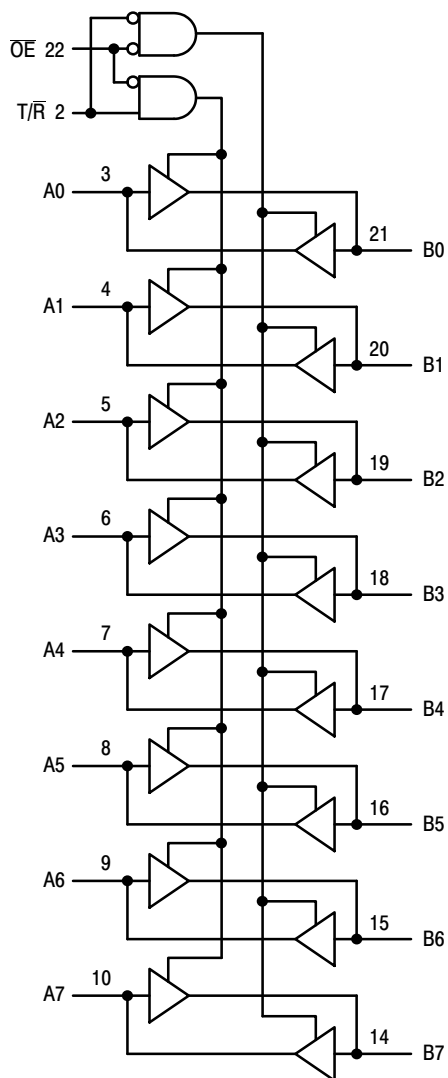


Figure 2. Logic Diagram

INPUTS		OPERATING MODE Non-Inverting
OE	T/R	
L	L	B Data to A Bus
L	H	A Data to B Bus
H	X	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions are Acceptable; For I_{CC} reasons, Do Not Float Inputs

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Condition	Value	Unit	
V_{CCA}, V_{CCB}	DC Supply Voltage		-0.5 to +6.5	V	
V_I	DC Input Voltage	$\overline{OE}, T/\overline{R}$	-0.5 to $V_{CCA} + 0.5$	V	
$V_{I/O}$	DC Input/Output Voltage	An	-0.5 to $V_{CCA} + 0.5$	V	
		Bn	-0.5 to $V_{CCB} + 0.5$	V	
I_{IK}	DC Input Diode Current	$\overline{OE}, T/\overline{R}$	$V_I < GND$	± 20	mA
I_{OK}	DC Output Diode Current		$V_O < GND; V_O > V_{CC}$	± 50	mA
I_O	DC Output Source/Sink Current		± 50	mA	
I_{CC}, I_{GND}	DC Supply Current	Per Output Pin Maximum Current at I_{CCA} Maximum Current at I_{CCB}	± 50 ± 200 ± 100	mA	
T_{STG}	Storage Temperature Range		-65 to +150	°C	
MSL	Moisture Sensitivity		Level 1	-	
V_{ESD}	ESD Withstand Voltage (Note 1)	Human Body Model	2000	V	
		Charged Device Model	1000		
$I_{Latchup}$	Latchup Performance (Note 2)		± 100	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- HBM tested to ANSI/ESDA/JEDEC JS-001-2023. CDM tested to ANSI/ESDA/JEDEC JS-002-2022. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
- Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CCA}, V_{CCB}	Supply Voltage	V_{CCA} 4.5 V_{CCB} 2.7	5.5 3.6	V
V_I	Input Voltage	$\overline{OE}, T/\overline{R}$	0 V_{CCA}	V
$V_{I/O}$	Input/Output Voltage	An	0 V_{CCA}	V
		Bn	0 V_{CCB}	
T_A	Operating Free-Air Temperature	-40	+85	°C
$\Delta t/\Delta V$	Minimum Input Edge Rate V_{IN} from 30% to 70% of V_{CC} ; V_{CC} at 3.0 V, 4.5 V, 5.5 V	0	8	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter		Condition	V_{CCA}	V_{CCB}	$T_A = 25\text{ }^\circ\text{C}$		$T_A = -40\text{ to }+85\text{ }^\circ\text{C}$		Unit
						Typ	Guaranteed Limits			
V_{IHA}	Minimum HIGH Level Input Voltage	An, \overline{OE} T/ \overline{R}	$V_{OUT} \leq 0.1\text{ V}$ or $\geq V_{CC} - 0.1\text{ V}$	5.5	3.3		2.0	2.0	V	
				4.5	3.3		2.0	2.0		
V_{IHB}		Bn		5.0	3.6		2.0	2.0	V	
				5.0	2.7		2.0	2.0		
V_{ILA}	Maximum LOW Level Input Voltage	An, \overline{OE} T/ \overline{R}	$V_{OUT} \leq 0.1\text{ V}$ or $\geq V_{CC} - 0.1\text{ V}$	5.5	3.3		0.8	0.8	V	
				4.5	3.3		0.8	0.8		
V_{ILB}		Bn		5.0	2.7		0.8	0.8	V	
				5.0	3.6		0.8	0.8		

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DC ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Condition	V _{CCA}	V _{CCB}	T _A = 25 °C		T _A = -40 to +85 °C		Unit
					Typ	Guaranteed Limits			
V _{OHA}	Minimum HIGH Level Output Voltage	I _{OUT} = -100 μA I _{OH} = -24 mA	4.5 4.5	3.0 3.0	4.50 4.25	4.40 3.86	4.40 3.76		V
V _{OHB}		I _{OUT} = -100 μA I _{OH} = -12 mA I _{OH} = -8 mA	4.5 4.5 4.5	3.0 3.0 2.7	2.99 2.80 2.50	2.9 2.4 2.4	2.9 2.4 2.4		V
V _{OLA}	Maximum LOW Level Output Voltage	I _{OUT} = 100 μA I _{OL} = 24 mA	4.5 4.5	3.0 3.0	0.002 0.18	0.10 0.36	0.10 0.44		V
V _{OLB}		I _{OUT} = 100 μA I _{OL} = 12 mA I _{OL} = 8 mA	4.5 4.5 4.5	3.0 3.0 2.7	0.002 0.1 0.1	0.10 0.31 0.31	0.10 0.40 0.40		V
I _{IN}	Max Input Leakage Current	OE, T/R	V _I = V _{CCA} , GND	5.5	3.6		±0.1	±1.0	μA
I _{OZA}	Max 3-State Output Leakage	A _n	V _I = V _{IH} , V _{IL} OE = V _{CCA} V _O = V _{CCA} , GND	5.5	3.6		±0.5	±5.0	μA
I _{OZB}	Max 3-State Output Leakage	B _n	V _I = V _{IH} , V _{IL} OE = V _{CCA} V _O = V _{CCB} , GND	5.5	3.6		±0.5	±5.0	μA
ΔI _{CC}	Maximum I _{CC} T per Input	A _n , OE T/R	V _I = V _{CCA} - 2.1 V	5.5	3.6	1.0	1.35	1.5	mA
		B _n	V _I = V _{CCB} - 0.6 V	5.5	3.6		0.35	0.5	mA
I _{CCA}	Quiescent V _{CCA} Supply Current		A _n = V _{CCA} or GND B _n = V _{CCB} or GND OE = GND T/R = GND	5.5	3.6		8	80	μA
I _{CCB}	Quiescent V _{CCB} Supply Current		A _n = V _{CCA} or GND B _n = V _{CCB} or GND OE = GND T/R = V _{CCA}	5.5	3.6		5	50	μA
V _{OLPA} V _{OLPB}	Quiet Output Max Dynamic V _{OL}		Notes 3, 4	5.0 5.0	3.3 3.3		1.5 1.2		V
V _{OLVA} V _{OLVB}	Quiet Output Min Dynamic V _{OL}		Notes 3, 4	5.0 5.0	3.3 3.3		-1.2 -0.8		V
V _{IHDA} V _{IHDB}	Min HIGH Level Dynamic Input Voltage		Notes 3, 5	5.0 5.0	3.3 3.3		2.0 2.0		V
V _{ILD} A V _{ILD} B	Max LOW Level Dynamic Input Voltage		Notes 3, 5	5.0 5.0	3.3 3.3		0.8 0.8		V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Worst case package.

4. Max number of outputs defined as (n). Data inputs are driven 0 V to V_{CC} level; one output at GND.

5. Max number of data inputs (n) switching. (n-1) inputs switching 0 V to V_{CC} level. Input under test switching: V_{CC} level to threshold (V_{IHD}), 0 V to threshold (V_{ILD}), f = 1 MHz.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typ	Unit
C _{IN}	Input Capacitance	V _{CCA} = 5.0 V; V _{CCB} = 3.3 V	4.5	pF
C _{I/O}	Input/Output Capacitance	V _{CCA} = 5.0 V; V _{CCB} = 3.3 V	15	pF
C _{PD}	Power Dissipation Capacitance (Measured at 10 MHz)	B → A	V _{CCA} = 5.0 V	55
		A → B	V _{CCB} = 3.3 V	40

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AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	$T_A = -40 \text{ to } +85 \text{ }^\circ\text{C}$ $C_L = 50 \text{ pF}$			$T_A = -40 \text{ to } +85 \text{ }^\circ\text{C}$ $C_L = 50 \text{ pF}$		Unit
		$V_{CCA} = 5 \text{ V} \pm 0.5 \text{ V}$ $V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$			$V_{CCA} = 5 \text{ V} \pm 0.5 \text{ V}$ $V_{CCB} = 2.7 \text{ V}$		
		Min	Typ (Note 6)	Max	Min	Max	
t_{PHL} t_{PLH}	Propagation Delay A to B	1.0 1.0	5.1 5.3	9.0 9.0	1.0 1.0	10.0 10.0	ns
t_{PHL} t_{PLH}	Propagation Delay B to A	1.0 1.0	5.4 5.5	9.0 9.0	1.0 1.0	10.0 10.0	ns
t_{PZL} t_{PZH}	Output Enable Time \overline{OE} to B	1.0 1.0	6.5 6.7	10.5 10.5	1.0 1.0	11.5 11.5	ns
t_{PZL} t_{PZH}	Output Enable Time \overline{OE} to A	1.0 1.0	5.2 5.8	9.5 9.5	1.0 1.0	10.0 10.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time \overline{OE} to B	1.0 1.0	6.0 3.3	10.0 7.0	1.0 1.0	10.0 7.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time \overline{OE} to A	1.0 1.0	3.9 2.9	7.5 7.0	1.0 1.0	7.5 7.5	ns
t_{OSHL} t_{OSLH}	Output to Output Skew, Data to Output (Note 7)		1.0	1.5		1.5	ns

6. Typical values at $V_{CCA} = 5.0 \text{ V}$; $V_{CCB} = 3.3 \text{ V}$ at $25 \text{ }^\circ\text{C}$.

7. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74LVX4245DWR2G	SOIC-24 (Pb-Free)	1000 / Tape & Reel
MC74LVX4245DTR2G	TSSOP-24 (Pb-Free)	2500 / Tape & Reel
MC74LVX4245DTR2G-Q*	TSSOP-24 (Pb-Free)	2500 / Tape & Reel

DISCONTINUED (Note 8)

MC74LVX4245DWG	SOIC-24 (Pb-Free)	30 Units / Rail
MC74LVX4245DTG	TSSOP-24 (Pb-Free)	62 Units / Rail
NLVLVX4245DTR2G*		2500 / Tape & Reel

[†] For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

* NLV Prefix or -Q suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

8. **DISCONTINUED:** These devices are not available. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

Dual Supply Octal Translating Transceiver

The 74LVX4245 is a dual-supply device well capable of bidirectional signal voltage translation. This level shifting ability provides an excellent interface between low voltage CPU local bus and a standard 5.0 V I/O bus. The device control inputs can be controlled by either the low voltage CPU and core logic or a bus arbitrator with 5.0 V I/O levels.

The LVX4245 is ideal for mixed voltage applications such as notebook computers using a 3.3 V CPU and 5.0 V peripheral devices.

Applications:

Mixed Mode Dual Supply Interface Solutions

The LVX4245 is designed to solve 3.0 V / 5.0 V interfaces when CMOS devices cannot tolerate I/O levels above their applied V_{CC} . If an I/O pin of a 3.0 V device is driven by a 5.0 V device, the P-Channel transistor in the 3.0 V device will conduct – causing current flow from the I/O bus to the 3.0 V power supply. The result may be destruction of the 3.0 V device through latchup effects. A current limiting resistor may be used to prevent destruction, but it causes speed degradation and needless power dissipation.

A better solution is provided in the LVX4245. It provides two different output levels that easily handle the dual voltage interface. The A port is a dedicated 5.0 V port; the B port is a dedicated 3.0 V port.

Since the LVX4245 is a '245 transceiver, the user may either use it for bidirectional or unidirectional applications. The center 20 pins are configured to match a '245 pinout. This enables the user to easily replace this level shifter with a 3.0 V '245 device without additional layout work or re-manufacture of the circuit board (when both buses are 3.0 V).

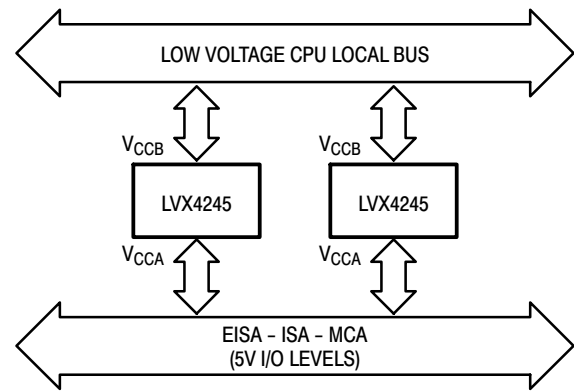


Figure 3. 3.3 V/5 V Interface Block Diagram

Powering Up the LVX4245

When powering up the LVX4245, please note that if the V_{CCB} pin is powered-up well in advance of the V_{CCA} pin, several milliamps of either I_{CCA} or I_{CCB} current will result. If the V_{CCA} pin is powered-up in advance of the V_{CCB} pin then only nanoamps of I_{cc} current will result. In actuality the V_{CCB} can be powered “slightly” before the V_{CCA} without the current penalty, but this “setup time” is dependent on the power-up ramp rate of the V_{CC} pins. With a ramp rate of approximately 50 mV/ns (50 V/ μ s) a 25 ns setup time was observed (V_{CCB} before V_{CCA}). With a 7.0 V/ μ s rate, the setup time was about 140 ns. When all is said and done, the safest powerup strategy is to simply power V_{CCA} before V_{CCB} . One more note: if the V_{CCB} ramp rate is faster than the V_{CCA} ramp rate then power problems might still occur, even if the V_{CCA} powerup began prior to the V_{CCB} powerup.

MC74LVX4245

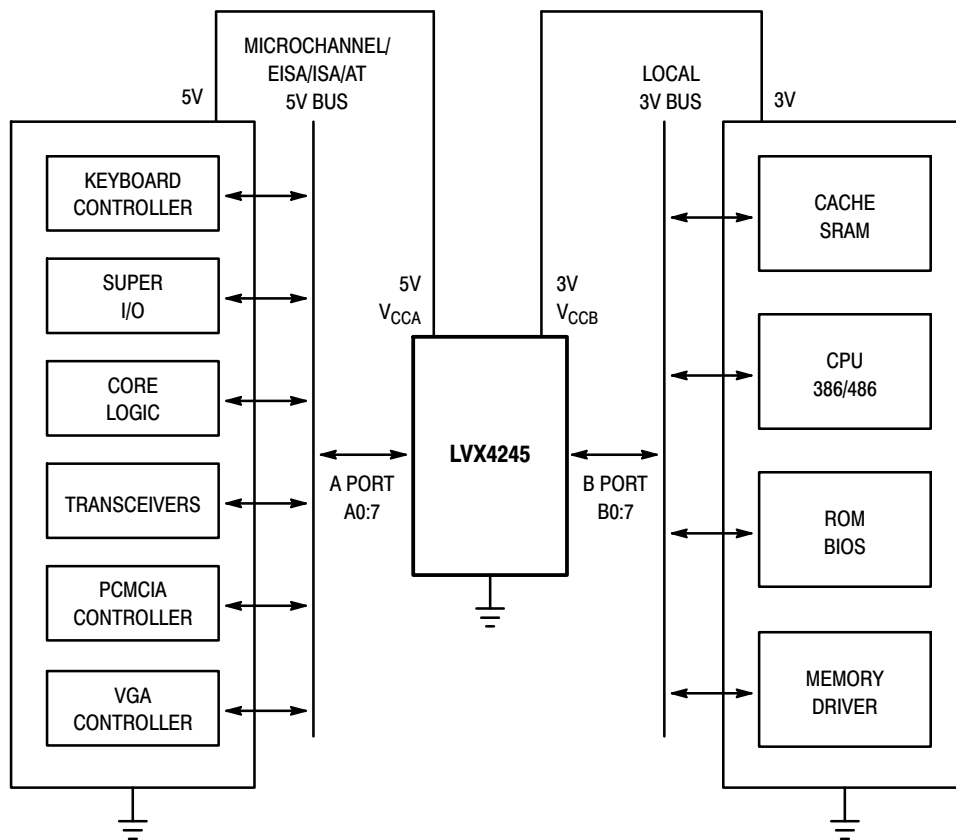


Figure 4. MC74LVX4245 Fits Into a System with 3 V Subsystem and 5 V Subsystem

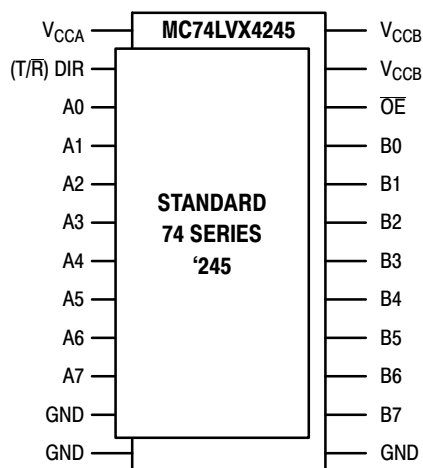
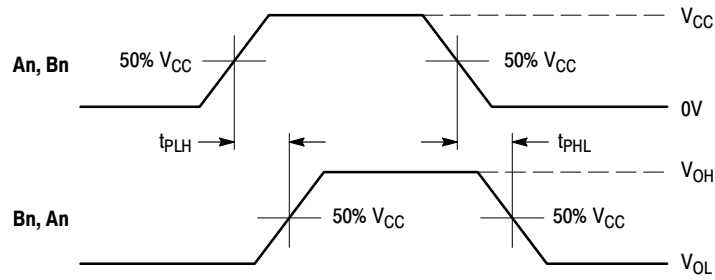
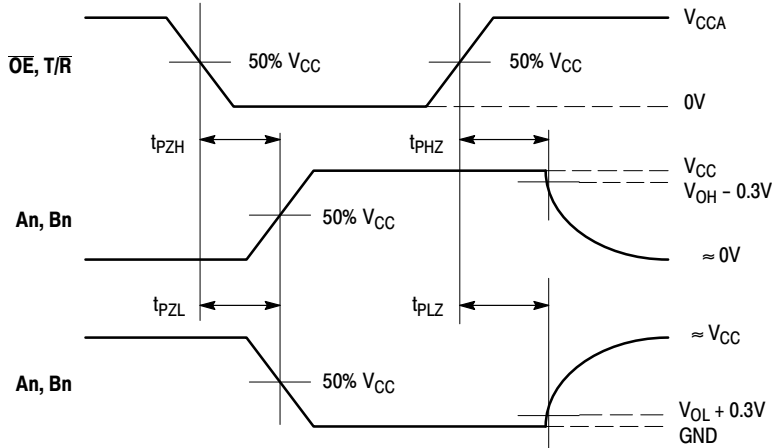


Figure 5. MC74LVX4245 Pin Arrangement Is Compatible to 20-Pin 74 Series '245s

MC74LVX4245

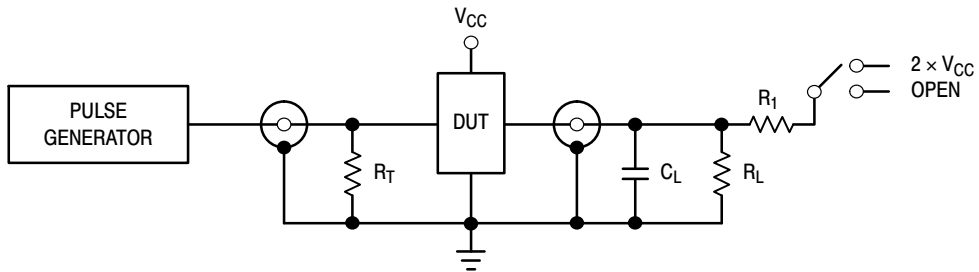


WAVEFORM 1 - PROPAGATION DELAYS
 $t_R = t_F = 2.5\text{ns}$, 10% to 90%; $f = 1\text{MHz}$; $t_W = 500\text{ns}$



WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES
 $t_R = t_F = 2.5\text{ ns}$, 10% to 90%; $f = 1\text{ MHz}$; $t_W = 500\text{ ns}$

Figure 6. AC Waveforms



TEST	SWITCH
t_{PLH} , t_{PHL} , t_{PZH} , t_{PHZ}	Open
t_{PZL} , t_{PLZ}	$2 \times V_{CC}$

$C_L = 50\text{ pF}$ or equivalent (Includes jig and probe capacitance)
 $R_L = R_1 = 500\ \Omega$ or equivalent
 $R_T = Z_{OUT}$ of pulse generator (typically $50\ \Omega$)

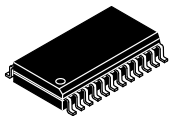
Figure 7. Test Circuit

MC74LVX4245

REVISION HISTORY

Revision	Description of Changes	Date
8	Added one new OPN and updated Latchup value.	5/8/2026
9	Updated Maximum Ratings table.	6/8/2026

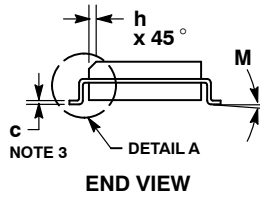
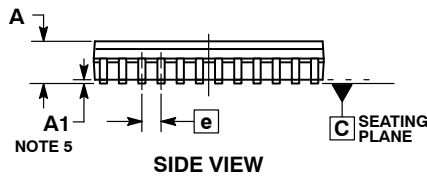
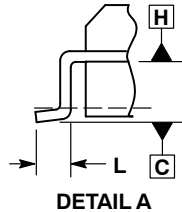
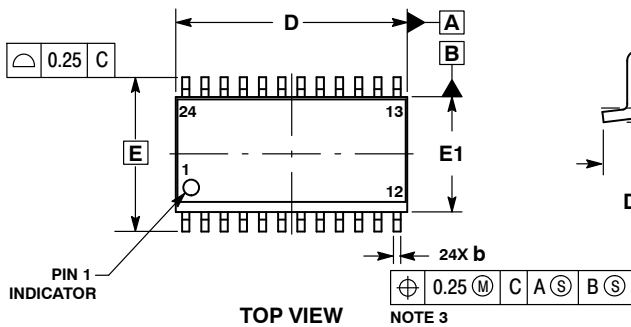
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.



SCALE 1:1

SOIC-24 WB
CASE 751E-04
ISSUE F

DATE 03 JUL 2012

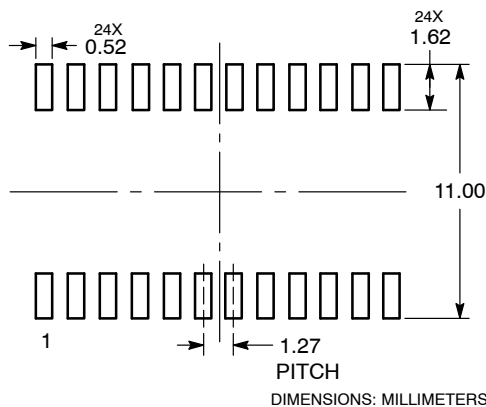


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD AND ARE MEASURED BETWEEN 0.10 AND 0.25 FROM THE LEAD TIP.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER SIDE. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
5. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

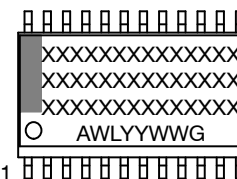
MILLIMETERS		
DIM	MIN	MAX
A	2.35	2.65
A1	0.13	0.29
b	0.35	0.49
c	0.23	0.32
D	15.25	15.54
E	10.30 BSC	
E1	7.40	7.60
e	1.27 BSC	
h	0.25	0.75
L	0.41	0.90
M	0°	8°

RECOMMENDED
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*

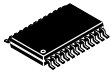


- XXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98ASB42344B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	SOIC-24 WB	PAGE 1 OF 1

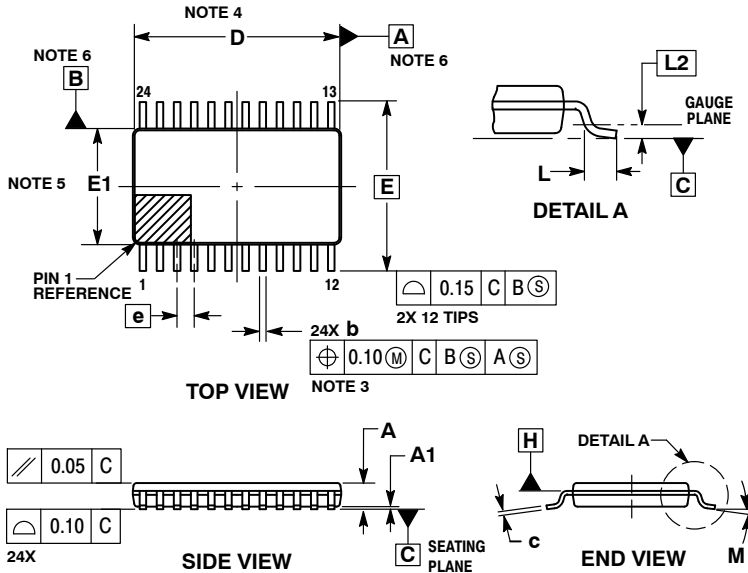
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SCALE 1:1

TSSOP24 7.8x4.4, 0.65P
CASE 948H
ISSUE B

DATE 21 JUN 2012

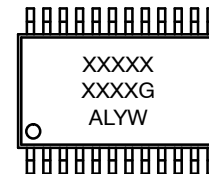


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. DAMBAR PROTRUSION SHALL BE 0.08 MAX AT MMC. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.
4. DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION D IS DETERMINED AT DATUM PLANE H.
5. DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 PER SIDE. DIMENSION E1 IS DETERMINED AT DATUM PLANE H.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
7. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

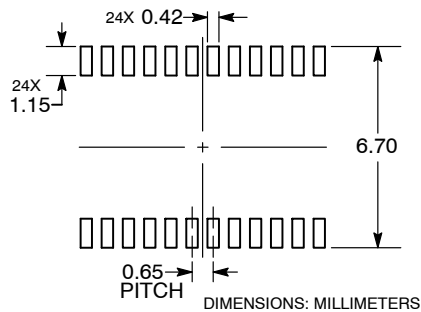
DIM	MILLIMETERS	
	MIN	MAX
A	---	1.20
A1	0.05	0.15
b	0.19	0.30
c	0.09	0.20
D	7.70	7.90
E	6.40 BSC	
E1	4.30	4.50
e	0.65 BSC	
L	0.50	0.75
L2	0.25 BSC	
M	0°	8°

GENERIC MARKING DIAGRAM*



- XXXX = Specific Device Code
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- G = Pb-Free Package

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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